

P-Channel MOSFET MEM2307M3G

General Description

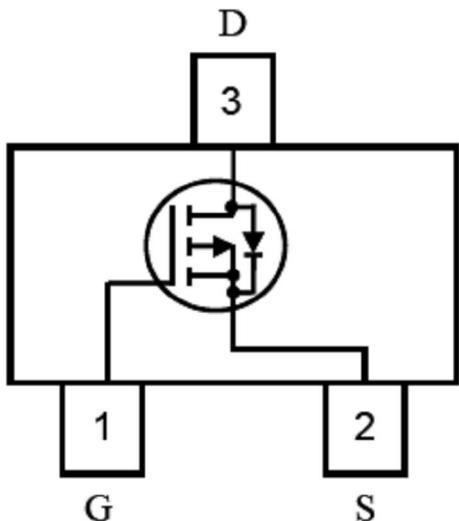
MEM2307M3G Series P-channel enhancement mode field-effect transistor ,produced with high cell density DMOS trench technology, which is especially used to minimize on-state resistance. This device particularly suits low voltage applications, and low power dissipation, and low power dissipation in a very small outline surface mount package.

Features

- | I -30V/-4.1A
- | $R_{DS(ON)} < 88m\Omega @ V_{GS}=-10V, I_D=-4.1A$
- | $R_{DS(ON)} < 108m\Omega @ V_{GS}=-4.5V, I_D=-3A$
- | I High Density Cell Design For Ultra Low On-Resistance
- | I Subminiature surface mount package: SOT23-3

Pin Configuration

Typical Application



- | I Power management
- | I Load switch
- | I Battery protection

Absolute Maximum Ratings

Parameter		Symbol	Ratings	Unit
Drain-Source Voltage		V_{DSS}	-30V	V
Gate-Source Voltage		V_{GSS}	± 20	V
Drain Current Current	$T_A=25$	I_D	-4.1	A
	$T_A=70$		-3.5	
Pulsed Drain Current ^{1,2}		I_{DM}	-20	A
Total Power Dissipation	$T_A=25$	P_d	1.4	W
	$T_A=70$		1	
Operating Temperature Range		T_{Opr}	150	
Storage Temperature Range		T_{stg}	-55/150	

Thermal Characteristics

Parameter		Symbol	TYP.	MAX.	Unit
Thermal Resistance, Junction-to-Ambient	t 10s	R _{JA}	65	90	/W
Thermal Resistance, Junction-to-Ambient	Steady-State	R _{JA}	85	125	/W
Thermal Resistance, Junction-to-Lead	Steady-State	R _{JL}	43	60	/W

Electrical Characteristics

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250uA	-30			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250uA	-1	-1.3	-2	V
Gate-Body Leakage	I _{GSS}	V _{DS} =0V , V _{GS} =20V			100	nA
		V _{DS} =0V , V _{GS} =-20V			-100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-24V V _{GS} =0V			-1000	nA
Static Drain-Source On-Resistance	R _{DS(ON)1}	V _{GS} =-10V,I _D =-4.1A			88	m
	R _{DS(ON)2}	V _{GS} =-4.5V,I _D =-3A			108	m
Forward Transconductance	g _{FS}	V _{DS} = -5 V, I _D = -4A	5.5	8.2		S
Maximum Body-Diode Continuous Current	I _S				-2.2	A
Source-drain (diode forward) voltage	V _{SD}	V _{GS} =0V,I _D =-1A	0.77	-1.0		V
Dynamic Characteristics						
Input Capacitance	C _{iss}	VGS=0V, VDS=-15V, f=1MHz		700	840	pF
Output Capacitance	C _{oss}			120		
Reverse Transfer Capacitance	C _{rss}			75		
Gate resistance	R _g	VGS=0V, VDS=0V, f=1MHz		10	15	
Switching Characteristics						
Turn-On Delay Time	td(on)	VGS=-10V,VDS=-15V, RL=3.6 ,RGEN=6		8.6		ns
Rise Time	tr			5		
Turn-Off Delay Time	td(off)			28.2		
Fall-Time	tf			13.5		
Total Gate Charge	Q _g	V _{DS} = -15 V, V _{GS} = -4.5 V, I _D = -4A		14.3		nc
Gate-Source Charge	Q _{gs}			3.1		
Gate-Drain Charge	Q _{gd}			3		

1、Repetitive rating, pulse width limited by junction temperature.

2、The static characteristics are obtained using 80 μ s pulses, duty cycle 0.5% max.

Typical Performance Characteristics

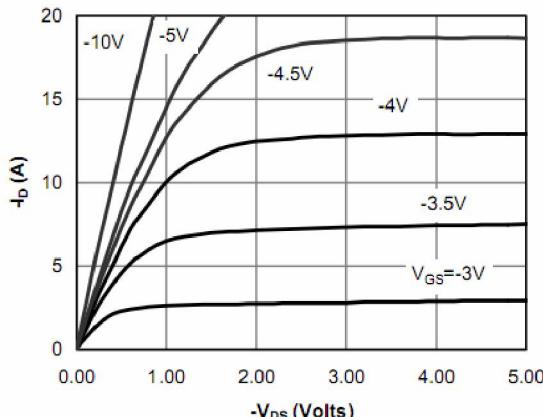


Figure 1: On-Region Characteristics

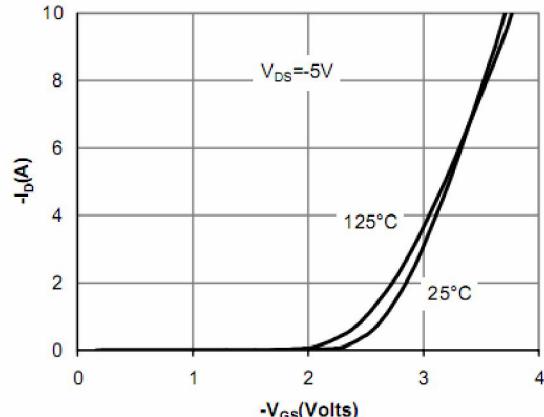


Figure 2: Transfer Characteristics

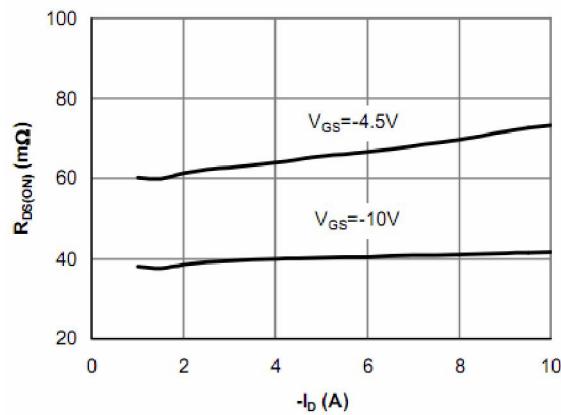


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

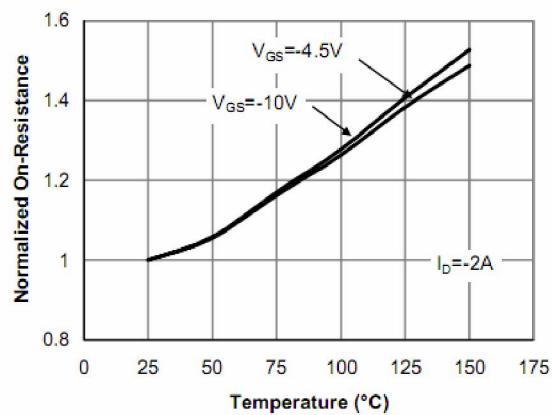


Figure 4: On-Resistance vs. Junction Temperature

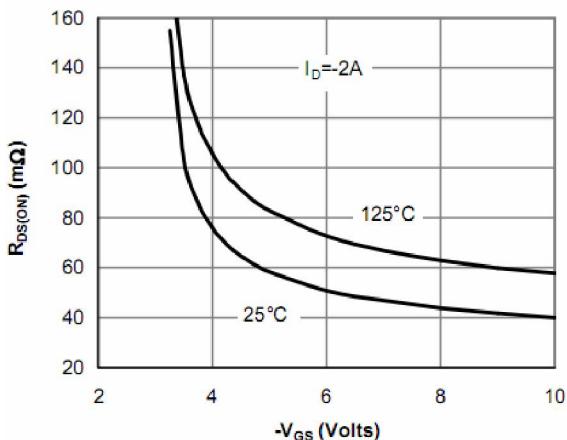


Figure 5: On-Resistance vs. Gate-Source Voltage

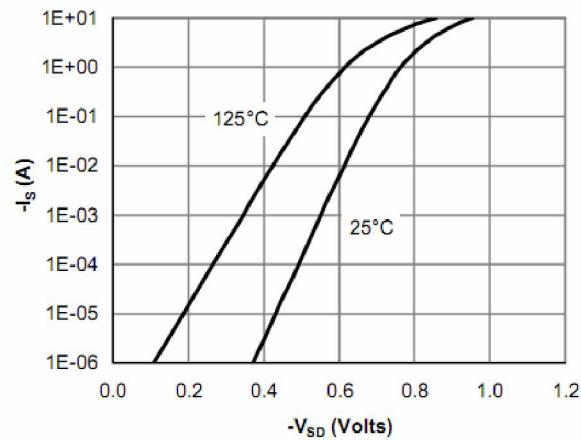
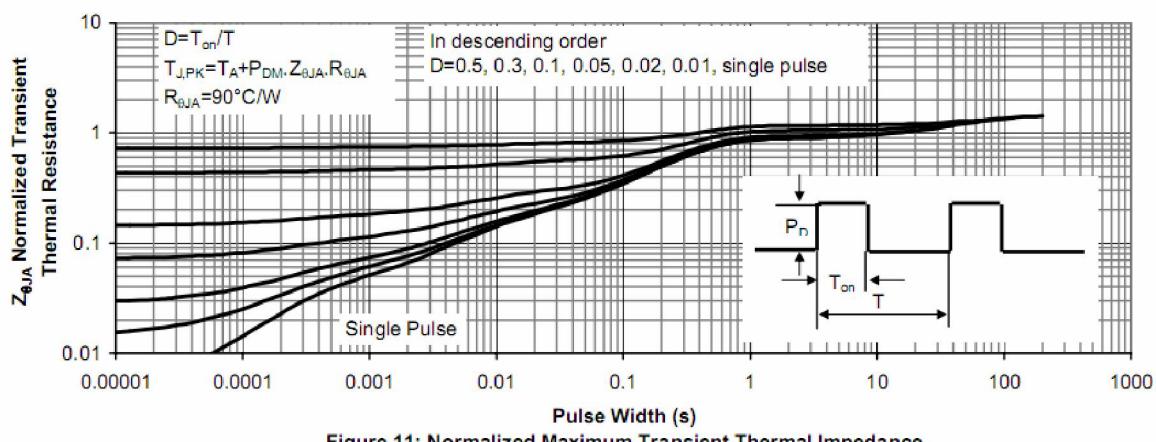
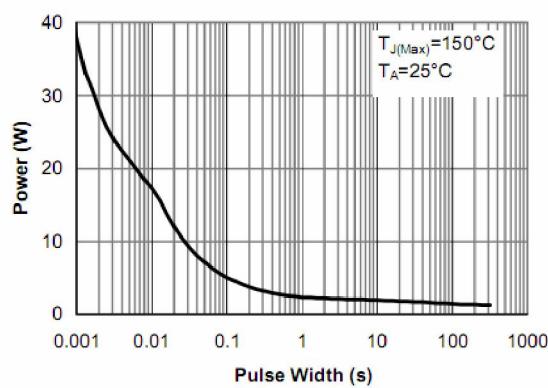
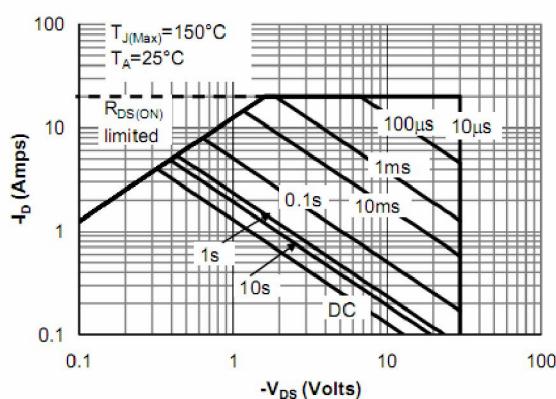
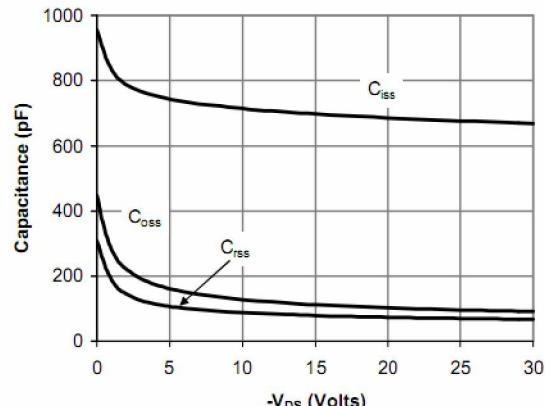
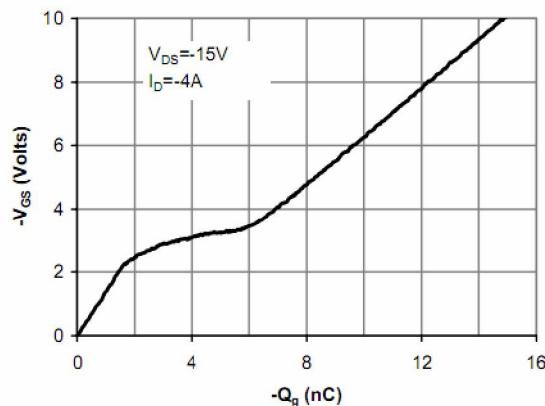
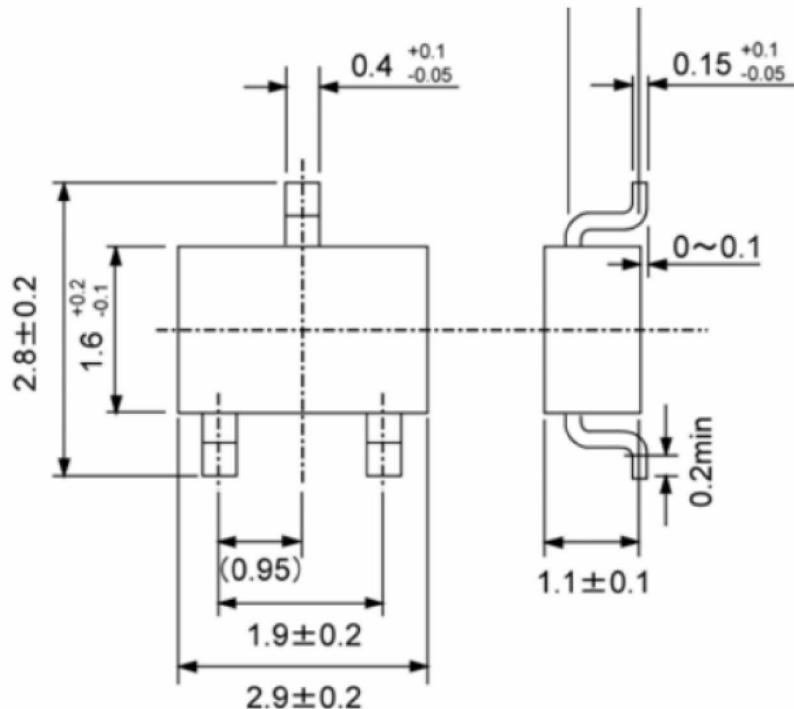


Figure 6: Body-Diode Characteristics



Package Information

Packaging Type: SOT23-3



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